NSN 5961-01-347-5850

A110a0

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-347-5850 **Inclosure Material:** Metal and ceramic **Overall Length:** Between 0.545 inches and 0.605 inches **Overall Diameter:** Between 1.850 inches and 1.900 inches **End Application:** Radar set an/mpn-14k **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1400.0 repetitive peak off-state voltage and 1400.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 450.00 amperes on-state current, average **Special Features:** Polytetrafluoroethylene tubing over insulated wire leads **Terminal Type And Quantity:** 2 case and 2 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: